Preferred Device

High Voltage Transistor

PNP Silicon

Features

• Pb-Free Packages are Available

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|-----------|-------|------|
| Collector - Emitter Voltage | V_{CEO} | -150 | Vdc |
| Collector - Base Voltage | V_{CBO} | -160 | Vdc |
| Emitter-Base Voltage | V_{EBO} | -5.0 | Vdc |
| Collector Current – Continuous | Ic | -500 | mAdc |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

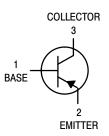
| Characteristic | Symbol | Max | Unit |
|---|-----------------------------------|-------------|-------|
| Total Device Dissipation FR-5 Board (Note 1) T _A = 25°C | P _D | 225 | mW |
| Derate Above 25°C | | 1.8 | mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate (Note 2) T _A = 25°C | P _D | 300 | mW |
| Derate Above 25°C | | 2.4 | mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

- 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.



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MARKING

2L = Device Code M = Month Code

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------|---------------------|-----------------------|
| MMBT5401LT1 | SOT-23 | 3000 Tape & Reel |
| MMBT5401LT1G | SOT-23 (Pb-Free) | 3000 Tape & Reel |
| MMBT5401LT3 | SOT-23 | 10,000 Tape & Reel |
| MMBT5401LT3G | SOT-23 (Pb-Free) | 10,000 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted) | Construct | NA: | Mari | 11:4 |
|--|----------------------|----------------|---------------|--------------|
| Characteristic | Symbol | Min | Max | Unit |
| OFF CHARACTERISTICS | | | | |
| Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mAdc}, I_B = 0)$ | V _{(BR)CEO} | -150 | _ | Vdc |
| Collector – Base Breakdown Voltage $(I_C = -100 \mu Adc, I_E = 0)$ | V _{(BR)CBO} | -160 | - | Vdc |
| Emitter – Base Breakdown Voltage $(I_E = -10 \mu Adc, I_C = 0)$ | V _{(BR)EBO} | -5.0 | - | Vdc |
| Collector Cutoff Current $(V_{CB} = -120 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -120 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$ | I _{CES} | - - | -50 -50 | nAdc μAdc |
| ON CHARACTERISTICS | | | | |
| DC Current Gain $ \begin{aligned} &(I_C = -1.0 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \\ &(I_C = -10 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \\ &(I_C = -50 \text{ mAdc, } V_{CE} = -5.0 \text{ Vdc)} \end{aligned} $ | h _{FE} | 50 60 50 | - 240 - | - |
| Collector – Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc) | V _{CE(sat)} | _ _ | -0.2 -0.5 | Vdc |
| Base – Emitter Saturation Voltage ($I_C = -10$ mAdc, $I_B = -1.0$ mAdc) ($I_C = -50$ mAdc, $I_B = -5.0$ mAdc) | V _{BE(sat)} | - - | -1.0 -1.0 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | |
| Current – Gain — Bandwidth Product $(I_C = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}, f = 100 \text{ MHz})$ | f⊤ | 100 | 300 | MHz |
| Output Capacitance $(V_{CB} = -10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$ | C _{obo} | - | 6.0 | pF |
| Small Signal Current Gain ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$) | h _{fe} | 40 | 200 | - |
| Noise Figure (I _C = $-200 \mu\text{Adc}$, V _{CE} = -5.0Vdc , R _S = 10Ω , f = 1.0kHz) | NF | _ | 8.0 | dB |

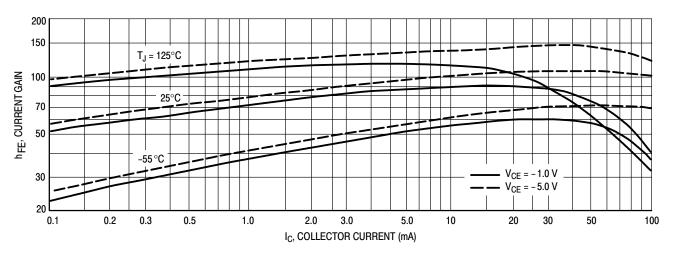


Figure 1. DC Current Gain

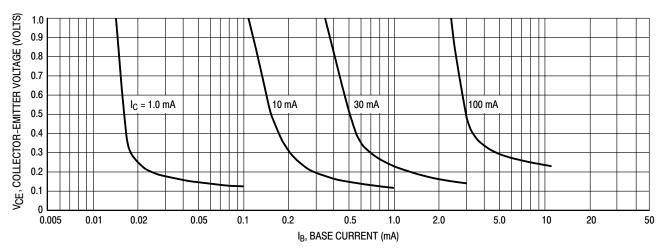


Figure 2. Collector Saturation Region

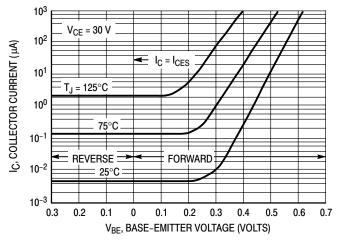


Figure 3. Collector Cut-Off Region

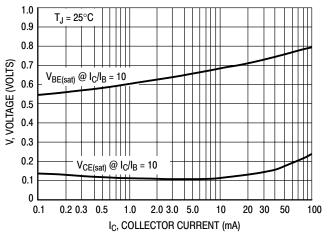


Figure 4. "On" Voltages

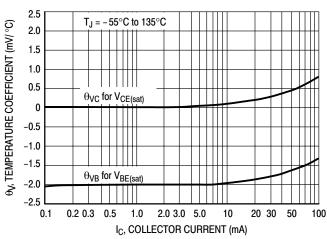
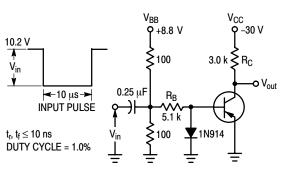


Figure 5. Temperature Coefficients



Values Shown are for I_C @ 10 mA

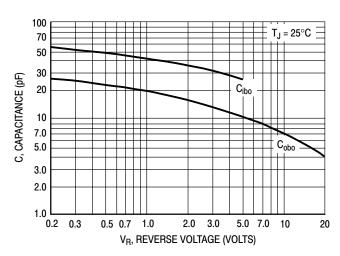


Figure 7. Capacitances

Figure 6. Switching Time Test Circuit

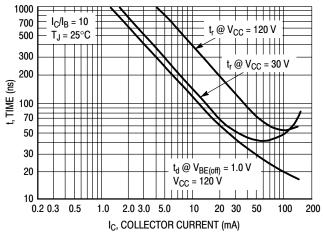


Figure 8. Turn-On Time

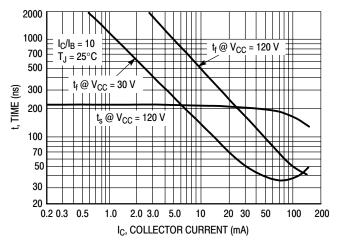
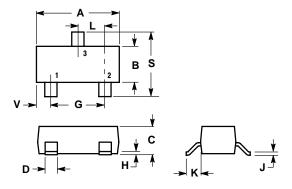


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS

SOT-23-3 (TO-236) CASE 318-08 **ISSUE AK**



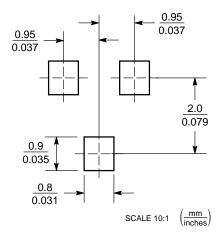
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

| | INCHES | | MILLIM | IETERS |
|-----|--------|--------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.1102 | 0.1197 | 2.80 | 3.04 |
| В | 0.0472 | 0.0551 | 1.20 | 1.40 |
| С | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| Н | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

STYLE 6:

- PIN 1. BASE 2. EMITTER
 - COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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